

US-Lasers: 635nm-5mW - Red Laser Diode and Red Diode Laser Module

Links to Laser Diode & Laser Module Configurations and Specifications
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[Laser Diodes](#) [Laser Diode Module](#) [Micro Laser Module](#) [Variable Output Laser Diode Module](#)

[N635-5](#) [NM635-5](#) [MM635-5](#) [EPM635-5](#)

DATA SHEETS MM635nm 5mWRED LASER MODULE		
Barrel Specs:	Weight & Wire Lengths:	Lens Housing Specs:
<ul style="list-style-type: none"> • 2 Pieces • 12 - 56 Thread Size • Dia: 6.4mm • Length: 17mm 	<ul style="list-style-type: none"> • Module with 6" wire leads - 49 grain wt.b • Module without 6" wire leads - 42 grain wt • Module with spring leads - 42 1/2 grain wt. • Spring 2.4mm dia. 4mm long (trimmable) 	<ul style="list-style-type: none"> • 12 - 56 Thread Size • 3.0mm Aperture • 4.0mm Plastic Lens

RED LASER DIODE DATA SHEET

ABSOLUTE MAXIMUM RATINGS - (Tc=25 °C)

C)

<p>TECHNICAL DATA</p> <p>Visible laser diode light output 635nm</p> <p>Optical power output 5mW CW</p> <p>Package Type 5.6mm</p> <p>Built-in photo diode for monitoring laser output</p>	<p>Pin Out Diagram</p>
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Items	Symbols	Values	Unit
Optical output power	P _o	5	mW
Laser diode reverse voltage	V	2	V
Photo diode reverse voltage	V	30	V
Operating temperature	Topr	-10 ~ +40	°C
Storage temperature	Tstg	-40 ~ +85	°C

OPTICAL and ELECTRICAL CHARACTERISTICS - (Tc=25 °C)

Items	Symbols	Min.	Typ.	Max.	Unit	Test Condition
Optical output power	P _o	-	-	5	mW	Kink free
Threshold current	I _{th}	30	35	45	mA	P _o =5mW
Operating current	I _{op}	-	45	70	mA	P _o =5mW
Operating voltage	V _{op}	-	-	2.5	V	P _o =5mW
Lasing wavelength		630	635	645	nm	P _o =5mW
Beam divergence		5	8	11	deg	P _o =5mW

Beam divergence		25	31	37	deg	$P_o=5mW$
Off Axis Angle		-	-	+/-3	deg	
Off Axis Angle		-	-	+/-3	deg	
Monitor current	I_m	-	35	-	uA	$P_o=5mW, V_R=5V$
Astigmatism	A_s	-	11	-	um	$P_o=5mW, NA=0.4$
MTTF				3-5,000 hrs.		$P_o=5mW$
Emitter Size		10 x 60 Microns - Emitter Distance to Cap Lens = 0.3mm				
Structure		IIIGaInP MQW				